January 2004



SEMICONDUCTOR®

# FDZ202P

## P-Channel 2.5V Specified PowerTrench<sup>®</sup> BGA MOSFET

#### **General Description**

Combining Fairchild's advanced 2.5V specified PowerTrench process with state of the art BGA packaging, the FDZ202P minimizes both PCB space and  $R_{DS(ON)}$ . This BGA MOSFET embodies a breakthrough in packaging technology which enables the device to combine excellent thermal transfer characteristics, high current handling capability, ultralow profile packaging, low gate charge, and low  $R_{DS(ON)}$ .

### Applications

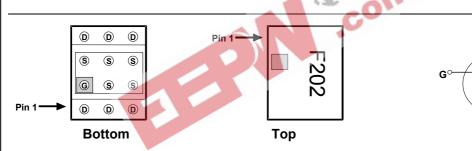
- Battery management
- Load switch
- Battery protection

#### Features

- $-5.5 \text{ A}, -20 \text{ V}. \text{ R}_{\text{DS(ON)}} = 45 \text{ m}\Omega \text{ @ } \text{V}_{\text{GS}} = -4.5 \text{ V}$  $\text{R}_{\text{DS(ON)}} = 75 \text{ m}\Omega \text{ @ } \text{V}_{\text{GS}} = -2.5 \text{ V}$
- Occupies only 5 mm<sup>2</sup> of PCB area: only 55% of the area of SSOT-6
- Ultra-thin package: less than 0.80 mm height when mounted to PCB

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- Outstanding thermal transfer characteristics: 4 times better than SSOT-6
- Ultra-low  $Q_g \ge R_{DS(ON)}$  figure-of-merit
- High power and current handling capability



## Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage		-20	V
V <sub>GSS</sub>	Gate-Source Voltage		±12	V
I <sub>D</sub>	Drain Current – Continuous	(Note 1a)	-5.5	А
	– Pulsed		-20	
PD	Power Dissipation (Steady State)	(Note 1a)	2	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

## **Thermal Characteristics**

$R_{ ext{ heta}JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	64	°C/W
$R_{ heta JB}$	Thermal Resistance, Junction-to-Ball	(Note 1)	8	°C/W
R <sub>0JC</sub>	Thermal Resistance, Junction-to-Case	(Note 1)	0.7	°C/W

## Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
202P	FDZ202P	7"	8mm	3000 units
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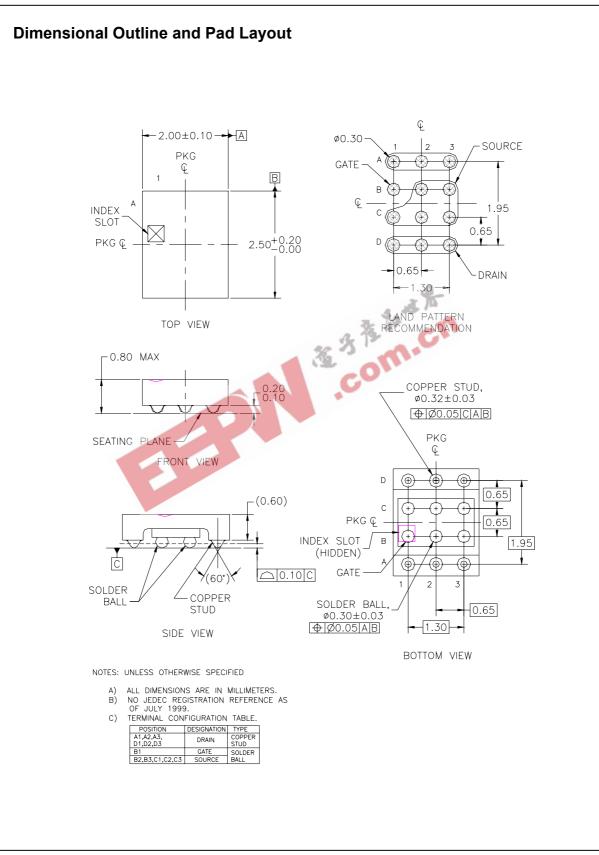
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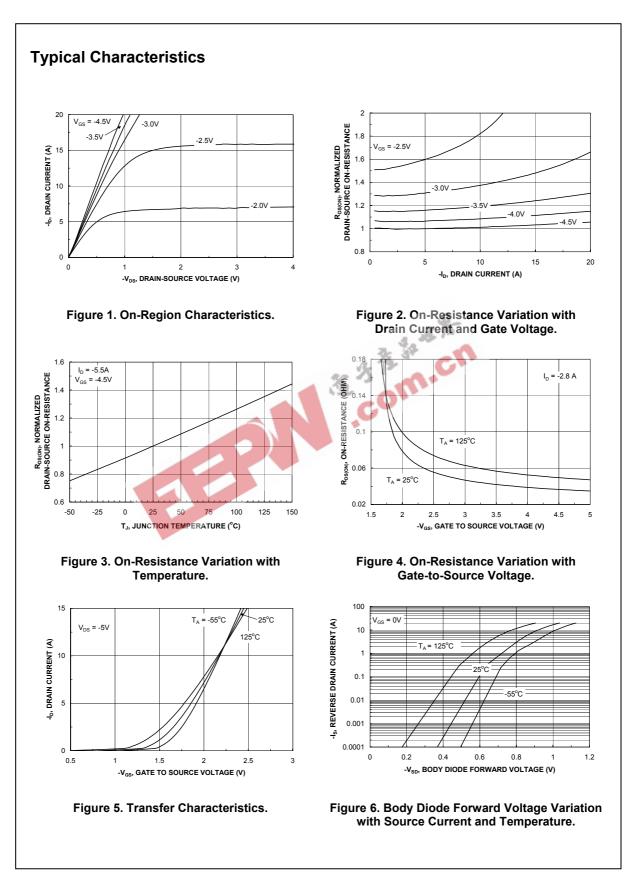
FDZ202P

2.

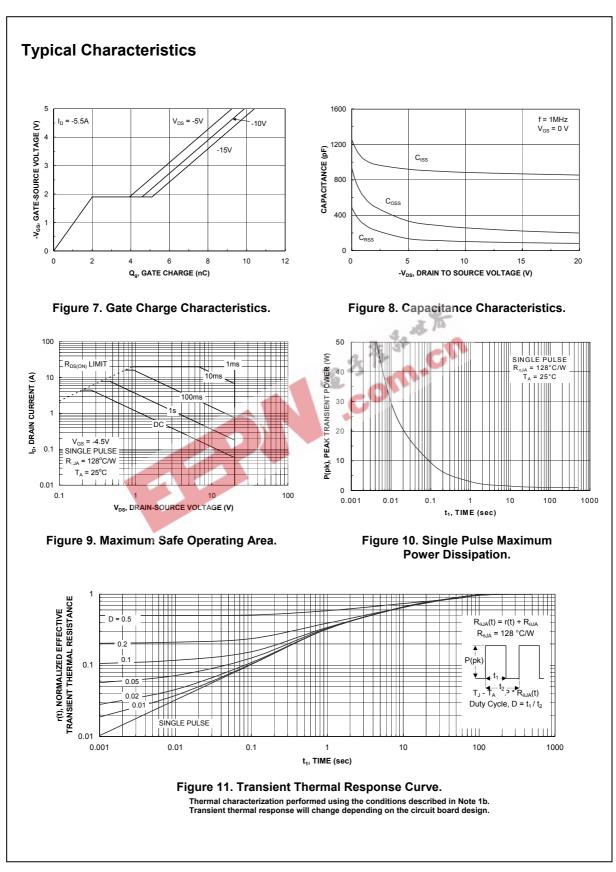
Pulse Test: Pulse Width <  $300\mu$ s, Duty Cycle < 2.0%



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ActiveArray™	FAST®	LittleFET™	Power247™	SuperSOT™-3
Bottomless™	FASTr™	MICROCOUPLER™	PowerTrench <sup>®</sup>	SuperSOT™-6
CoolFET™	FPS™	MicroFET™	QFET <sup>®</sup>	SuperSOT™-8
CROSSVOLT™	FRFET™	MicroPak™	QS™	SyncFET™
DOME™	GlobalOptoisolator™	MICROWIRE™	QT Optoelectronics <sup>™</sup>	TinyLogic®
EcoSPARK™	GTO™	MSX™	Quiet Series <sup>™</sup>	TINYOPTO™
E <sup>2</sup> CMOS <sup>™</sup>	HiSeC™	MSXPro™	RapidConfigure™	TruTranslation™
EnSigna™	I²C™	OCX™	RapidConnect™	UHC™
FACT™	ImpliedDisconnect™	OCXPro™	SILENT SWITCHER®	UltraFET <sup>®</sup>
Across the board	d. Around the world.™	<b>OPTOLOGIC<sup>®</sup></b>	SMART START™	VCX™
The Power France		OPTOPLANAR™	SPM™	
Programmable A		PACMAN™	Stealth™	

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